



7. The low resistive materials are also generally called as ----- materials. CO1-U  
 (a) Conducting (b) Non conducting (c) Semi conducting (d) Insulator
8. The electron is moving with a drift velocity of 4 m/s from one end of the wire to other end due to the applied electric field 2 V/m. Calculate the mobility of  $e^{-S}$ . CO2-U  
 (a)  $8 \text{ m}^2 \text{ V}^{-1} \text{ s}^{-1}$  (b)  $4 \text{ m}^2 \text{ V}^{-1} \text{ s}^{-1}$  (c)  $2 \text{ m}^2 \text{ V}^{-1} \text{ s}^{-1}$  (d)  $0.5 \text{ m}^2 \text{ V}^{-1} \text{ s}^{-1}$
9. \_\_\_\_\_ and silicon are two important elemental semiconductors. They are used in diodes and transistors. CO1-U  
 (a) Germanium (b) Aluminum (c) Copper (d) Dielectrics
10. The material emits photon during the transfer of electron from conduction band to valence band is CO1-U  
 (a) Silicon (b) Germanium (c) Gold (d) Gallium Arsenide

PART – B (5 x 2= 10 Marks)

11. What are Bravais Lattices? CO1-U
12. Why colours are formed in thin films? CO2-U
13. How is laser light different from an ordinary light? CO1-U
14. Define Fermi level and Fermi energy in metals with its importance. CO3-App
15. What are the differences between intrinsic & extrinsic semiconductor. CO3-App

PART – C (5 x 16= 80 Marks)

16. (a) A metallic crystal has a cubic structure. CO3-App (16)  
 (a) If the radius of an atom in the crystal is 0.125 nm and the crystal exhibits a body centered cubic (BCC) arrangement, calculate the edge length of the unit cell and its atomic packing factor (APF).  
 (b) For another metal with the same atomic radius but a face centered cubic (FCC) arrangement, calculate the edge length and atomic packing factor.  
 (c) Compare the packing efficiencies of the two structures and explain which structure allows closer atomic packing.
- Or
- (b) What are miller indices? Sketch two successive (110) planes. CO3- App (16)  
 Show that for a cubic lattice the distance between two successive planes (hkl) is given by

$$d = \frac{a}{\sqrt{h^2+k^2+l^2}}$$

17. (a) Discuss the theory of interference of light due to thin films by reflection with suitable ray diagram. CO2-U (16)  
 Or  
 (b) Explain the modes of vibrations of CO<sub>2</sub> molecule. By applying this theory, describe the construction and working of CO<sub>2</sub> laser with necessary diagrams. CO2-U (16)
18. (a) (i) State de-Broglie's hypothesis. Derive an expression for de-Broglie wavelength, in terms of energy E and accelerating potential V. CO1-U (8)  
 (ii) Explain the properties of matter waves CO1-U (8)  
 Or  
 (b) (i) Derive the Schrodinger's time independent wave equation CO1-U (8)  
 (ii) A neutron of mass  $1.675 \times 10^{-27}$  kg is moving with a kinetic energy 10 keV. Calculate the de-Broglie wavelength associated with it. CO1-U (8)
19. (a) (i) Deduce mathematical expressions for electrical conductivity and thermal conductivity of a conducting material. CO1-U (12)  
 (ii) What are the advantages of quantum free electron theory over classical free electron theory? CO1-U (4)  
 Or  
 (b) Obtain an expression for the density of states and carrier concentration in metals. CO1-U (16)
20. (a) Derive an expression for concentration of holes (absence of electrons) in intrinsic semiconductors. CO1-U (16)  
 Or  
 (b) Give the theory of Hall effect. Show that for a n-type semiconductor the Hall coefficient  $R_H$  is given by  $-1/ne$  CO1-U (16)

